NSN 5962-01-240-2353



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View Online at https://aerobasegroup.com/nsn/5962-01-240-2353
Body Length:
1.280 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
660.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and electrostatic sensitive and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-9 mil-m-38510
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:

5.00 input picofarads and 8.00 output picofarads

Time Rating Per Chacteristic:

35.00 nanoseconds delay

Memory Device Type:

Prom

Special Features:

Nuclear hardness critical item

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0